



#### GENERAL PURPOSE LOW VOLTAGE COMPARATOR

# **Description**

The LMV331/LMV393 series are low-voltage, (2.7V to 5.5V) single and dual comparators, which are designed to effectively reduce cost and space at low-voltage levels.

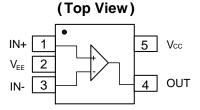
These devices offer specifications that meet or exceed the familiar LM331/LM393 devices operating with a lower supply voltage and consuming a far lower supply current.

The LMV331 is available in 5-Pin SOT353/SOT25 packages that reduce space on PC boards and portable electronic devices. LMV393 is available in industry standard SOP-8 and MSOP-8 packages.

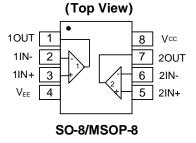
### **Features**

- Guaranteed 2.7V and 5.5V performance
- Operating temperature range (-40°C to +125°C)
- Low supply current 40 μA/comparator Typ
- Input Common Mode Voltage Range includes ground
- Open Collector Output for Maximums Flexibility
- SOT353, SOT25, MSOP-8, SO-8: Available in "Green" Molding Compound (No Br, Sb)
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

### **Pin Assignments**



### **SOT25/SOT353**



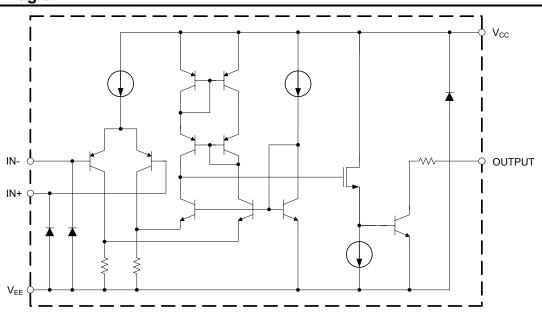
## **Applications**

- Mobile Communications
- Battery Powered Devices
- Notebooks and PDA's
- General Purpose Low-Voltage Applications
- General Purpose Portable Devices

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

# **Schematic Diagram**



**Each Comparator** 



# **Pin Descriptions**

LMV331		
Pin Name	Pin#	Function
IN+	1	Non-Inverting Input
$V_{EE}$	2	Chip Supply Voltage(Negative)/GND
IN-	3	Inverting Input
OUT	4	Output
V <sub>CC</sub>	5	Chip Supply Voltage(Positive)
LMV393		
1OUT	1	Channel 1 Output
1IN-	2	Channel 1 Inverting Input
1IN+	3	Channel 1 Non-inverting Input
V <sub>EE</sub>	4	Chip Supply Voltage(Negative)/GND
2IN+	5	Channel 2 Non-inverting Input
2IN-	6	Channel 2 Inverting Input
2OUT	7	Channel 2 Output
V <sub>CC</sub>	8	Chip Supply Voltage(Positive)

# Absolute Maximum Ratings (Note 4) (@TA = +25°C, unless otherwise specified.)

Symbol	Descriptio	Description		Unit
ESD HBM	Human Body Model ESD Protection		6.0	KV
ESD MM	Machine Model ESD Protection		200	V
$V_{ID}$	Differential Input Voltage		±Supply Voltage	V
V <sub>CC</sub> -V <sub>EE</sub>	Supply Voltage		5.5	V
	SOT353 (Note 5)	SOT353 (Note 5)	371	
0	Thermal Resistance Junction-to-	SOT25 (Note 5)	204	°C/W
$\theta_{JA}$	Ambient SO-8 (Note 5) MSOP-8 (Note 5)	SO-8 (Note 5)	120	C/VV
		MSOP-8 (Note 5)	180	
T <sub>ST</sub>	Storage Temperature		-65 to +150	°C
TJ	Maximum Junction Temperature		+150	°C

Notes:

# Recommended Operating Conditions (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
V <sub>CC</sub> -V <sub>EE</sub>	Supply Voltage	2.7 to 5.5	V
T <sub>A</sub>	Operating Ambient Temperature Range	-40 to +125	°C

Stresses greater than the 'Absolute Maximum Ratings' specified above, may cause permanent damage to the device. These are stress ratings only; functional operation of the device at these or any other conditions exceeding those indicated in this specification is not implied. Device reliability may be effected by exposure to absolute maximum rating conditions for extended periods of time.
 All numbers are typical, and apply for packages soldered directly onto a PC board in still air.



# $\hline \textbf{Electrical Characteristics} \text{ (Notes 6 \& 7) (@T_A = +25 °C, V_{EE} = 0 V, V_{CM} = 0 V \text{ and } R_L = 5.1 K\Omega, \text{ unless otherwise specified.)}$

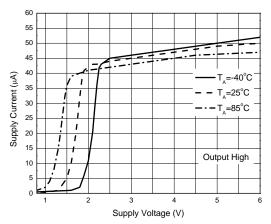
Symbol	Parameter		Test Conditions	Min	Тур	Max	Unit	
2.7V DC Electr	2.7V DC Electrical Characteristics							
Vos	Input Offset Voltage		-	=	1.7	7	mV	
TCVos	Input Offset Voltage Average Drift		T <sub>A</sub> = full range	-	5	-	μV/°C	
	Innut Dies Current		-	=	10	250	nA	
I <sub>B</sub>	Input Bias Current		T <sub>A</sub> = full range	-	-	400		
	In most Office to Commo		-	-	5	50	- 1	
los	Input Offset Curre	nt	T <sub>A</sub> = full range	=	-	150	nA	
V <sub>CM</sub>	Common-Mode In	put Voltage Range	-	-0.1	-	+2.0	V	
V <sub>SAT</sub>	Saturation Voltage	9	I <sub>SINK</sub> ≤ 1mA	-	120	-	mV	
Io	Output Sink Curre	ent	V <sub>O</sub> ≤ 1.5V	5	23	-	mA	
_			-	-	0.003	-	_	
I <sub>OL</sub>	Output Leakage C	Current	T <sub>A</sub> = full range	-	-	1	μΑ	
		LMV331	-	-	40	100	μA	
Is		LMV393 (Both Comparators)	-	-	70	150	uA	
2.7V AC Electr	ical Characteristics						ı	
			Input overdrive= 10mV	-	1,000	-	ns	
tpHL	Propagation delay	/ high to low	Input overdrive= 100mV	-	350	-	ns	
	Duana sation dala	. lata lainda	Input overdrive= 10mV	-	500	-	ns	
t <sub>PLH</sub>	Propagation delay	low to nign	Input overdrive= 100mV	-	400	-	ns	
5V DC Electric	al Characteristics							
\/	Input Offset Volta	90	-	-	1.7	7	mV	
Vos	Imput Offset Volta	y <del>e</del>	$T_A = full range$	-	-	9	IIIV	
TCVos	Input Offset Voltage Average Drift		T <sub>A</sub> = full range	•	5	-	μV/°C	
	I <sub>B</sub> Input Bias Current		-	•	25	250	nA	
IΒ			T <sub>A</sub> = full range	•	-	400	IIA	
Las	Input Offeet Curre	unt.	-	•	2	50	nA	
los	Input Offset Curre	er it	$T_A = full range$	-	-	150		
$V_{CM}$	Common-Mode Ir	put Voltage Range	-	-0.1	-	4.2	V	
Av	Large Signal Diffe	erential Voltage Gain	-	20	50	-	V/mV	
			I <sub>SINK</sub> ≤ 4mA	-	200	400	mV	
$V_{SAT}$	Saturation Voltage	е	I <sub>SINK</sub> ≤ 4mA, T <sub>A</sub> = full range	-	-	700		
Io	Output Sink Curre	ent	V <sub>O</sub> ≤ 1.5V	10	84	-	mA	
			-	-	0.003	-		
I <sub>OL</sub>	I <sub>OL</sub> Output Leakage Current		T <sub>A</sub> = full range	_	-	1	μA	
		110/00/		-	60	120		
		LMV331	T <sub>A</sub> = full range	-	-	150	μA	
Is	Supply Current	LMV393	-	-	100	200	<u> </u>	
	(Both Comparators)		T <sub>A</sub> =full range	-	-	250	uA	
5VAC Electrica	al Characteristics	•					•	
4-	Propagation data	, high to low	Input overdrive = 10mV	-	600	-	ns	
t <sub>PHL</sub>	Propagation delay	ringii to low	Input overdrive = 100mV	-	200	-	ns	
tour	Propagation delay	/ low to high	Input overdrive = 10mV	-	450	-	ns	
t <sub>PLH</sub> Propagation delay		, ion to mgm	Input overdrive = 100mV	-	300	-	ns	

Notes:

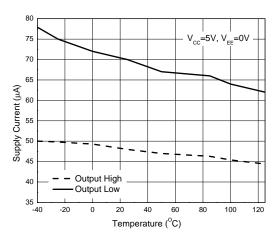
Typical values represent the most likely parametric norm as determined at the time of characterization. Actual typical values may vary over time and will
also depend on the application and configuration. The typical values are not tested and are not guaranteed on shipped production material.
 All limits are guaranteed by testing or statistical analysis.



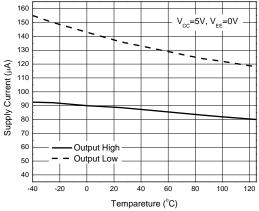
# Typical Performance Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



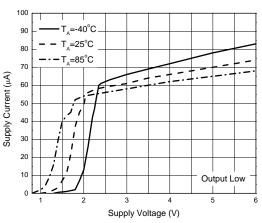
Supply Current vs. Supply Voltage (LMV331)



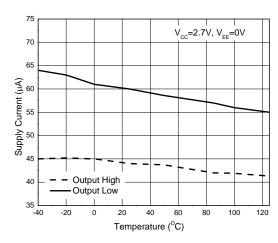
Supply Current vs. Temperature (LMV331)



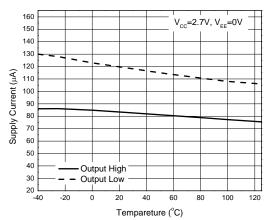
Supply Current vs. Temperature (LMV393)



Supply Current vs. Supply Voltage (LMV331)



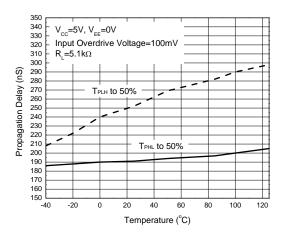
Supply Current vs. Temperature (LMV331)



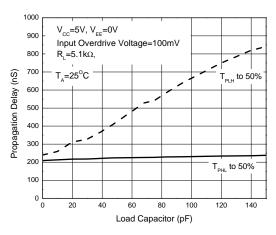
Supply Current vs. Temperature (LMV393)



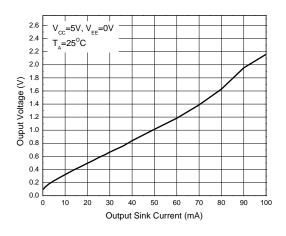
# Typical Performance Characteristics (continued) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)



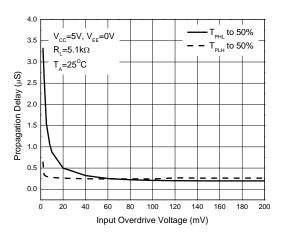
#### **Propagation Delay vs. Temperature**



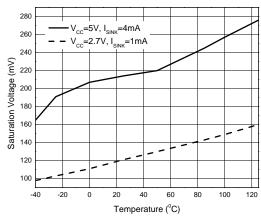
**Propagation Delay vs. Load Capacitors** 



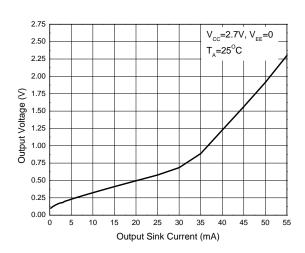
**Output Voltage vs. Output Sink Current** 



**Propagation Delay vs. Input Overdrive Voltage** 



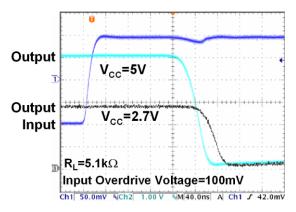
Saturation Voltage vs. Temperature



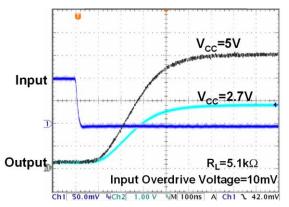
**Output Voltage vs. Output Sink Current** 



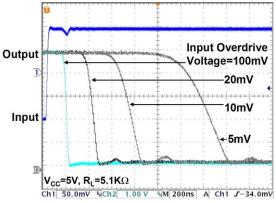
## Typical Performance Characteristics (cont.) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)



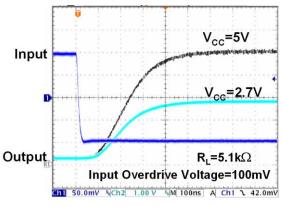
**Response Time for Positive Transition** 



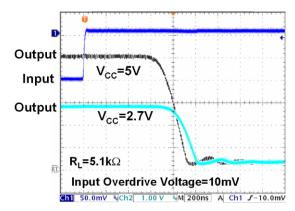
**Response Time for Negative Transition** 



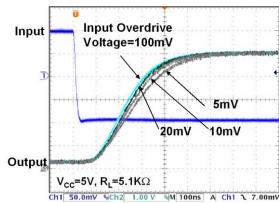
**Response Time for Positive Transition** 



**Response Time for Negative Transition** 



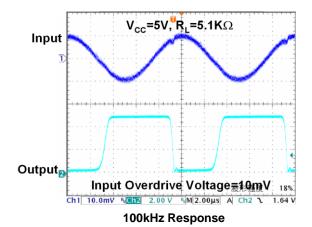
**Response Time for Positive Transition** 

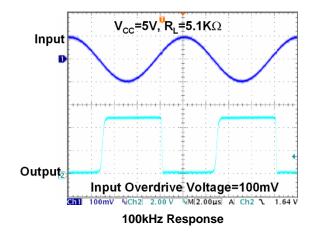


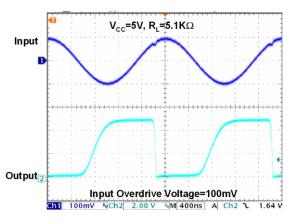
**Response Time for Negative Transition** 



# Typical Performance Characteristics (cont.) (@ T<sub>A</sub> = +25°C, unless otherwise specified.)







500kHz Response



# **Application Information**

### **Detailed Description**

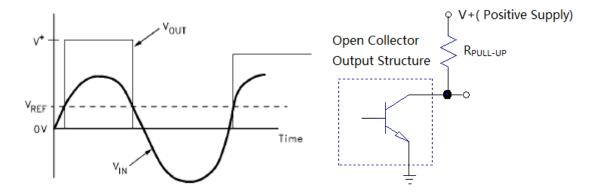
LMV331/LMV393 are low-voltage single/dual general- purpose comparators. They have a single supply operating voltage range from 2.7V to 5.5V; the common mode input voltage range extends from -0.1V below the negative supply to within 0.8V of the positive supply.

The LMV331/393 series is built using the BiCMOS process with bipolar input and output stages for improved noise performance. It is a cost-effective solution for portable consumer products where space, low voltage, low power and price are the primary specification in circuit design.

#### **Basic Comparator**

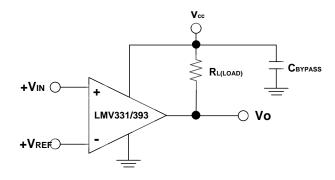
A basic comparator circuit is used for converting analog signal to digital output. The LMV331/393 has open-collector output structure, which required a pull-high resistor to positive supply voltage for the output to switch properly. When the internal output transistor is off, the output voltage will be pulled up to the external positive voltage.

The output pull- up resistor should be chosen high enough so as to avoid excessive power dissipation, yet low enough to supply enough drive to switch whatever load circuitry is used on the comparator output. On the LMV331/393 the pull-up resistor should range between  $1K\Omega$  to  $10K\Omega$ .



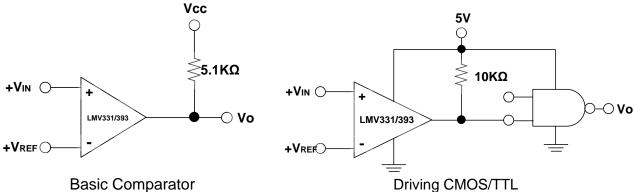
#### **Power Supply Bypassing**

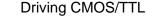
For better performance, power supply bypass capacitor is necessary. For a single-supply operation system, a minimum of  $0.1\mu F$  bypass capacitor should be recommended to place as close as possible between  $V_{CC}$  pin and GND.

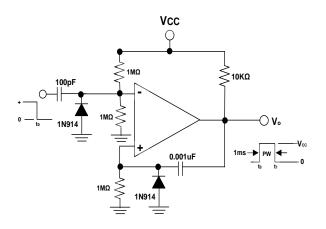




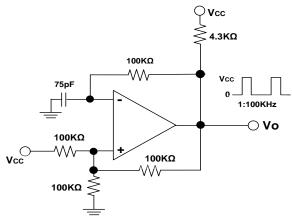
# **Typical Application Circuit**



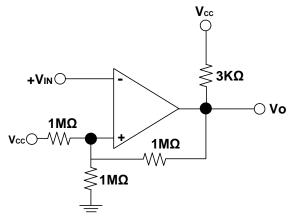




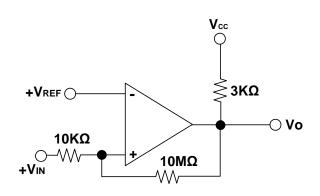
One-Shot Multivibrator



Squarewave Oscillator



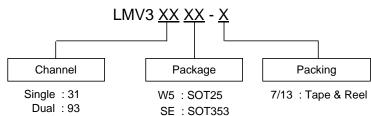
Inverting Comparator with Hysteresis



Non-Inverting Comparator with Hysteresis



# **Ordering Information**



S : SO-8 M8 : MSOP-8

Dant Number	Part Number Package Code	Packaging	7"/13" Tape and Reel		
Part Number			Quantity	Part Number Suffix	
LMV331W5-7	W5	SOT25	3,000/Tape & Reel	-7	
LMV331SE-7	SE	SOT353	3,000/Tape & Reel	-7	
LMV393S-13	S	SO-8	2,500/Tape & Reel	-13	
LMV393M8-13	M8	MSOP-8	2,500/Tape & Reel	-13	

# **Marking Information**

### (1) SOT25 and SOT353

### (Top View)

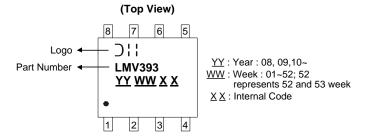
**XX Y W X** 

XX: Identification Code
Y: Year: 0~9
W: Week: A~Z: 1~26 week;
a~z: 27~52 week;
z represents 52 and 53 week

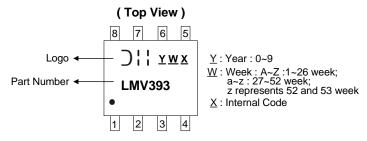
X : Internal Code

Device	Package type	Identification Code
LMV331W5	SOT25	CX
LMV331SE	SOT353	CY

### (2) SO-8



### (3) MSOP-8

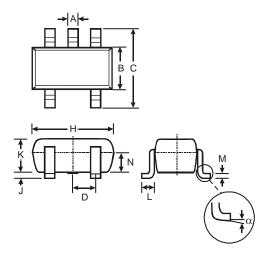




# Package Outline Dimensions (All dimensions in mm.)

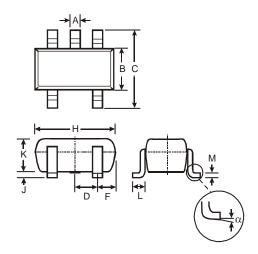
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

### (1) Package Type: SOT25



	SOT25				
Dim	Min	Max	Тур		
Α	0.35	0.50	0.38		
В	1.50	1.70	1.60		
U	2.70	3.00	2.80		
D			0.95		
Η	2.90	3.10	3.00		
7	0.013	0.10	0.05		
K	1.00	1.30	1.10		
L	0.35	0.55	0.40		
M	0.10	0.20	0.15		
N	0.70	0.80	0.75		
α	0°	8°	_		
All Dimensions in mm					

### (2) Package Type: SOT353



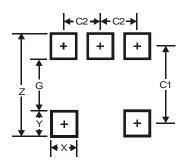
	SOT353			
Dim	Min	Max	Тур	
Α	0.10	0.30	0.25	
В	1.15	1.35	1.30	
С	2.00	2.20	2.10	
D	0	.65 Typ	)	
F	0.40	0.45	0.425	
Н	1.80	2.20	2.15	
J	0	0.10	0.05	
K	0.90	1.00	1.00	
L	0.25	0.40	0.30	
M	0.10	0.22	0.11	
α	0°	8°	-	
All Dimensions in mm				



# **Suggested Pad Layout**

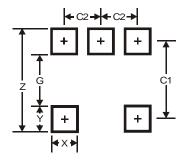
 $Please see AP02001 \ at \ http://www.diodes.com/datasheets/ap02001.pdf \ for \ the \ latest \ version.$ 

### (1) Package Type: SOT25



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

### (2) Package Type: SOT353



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Υ	0.6
C1	1.9
C2	0.65



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  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

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